

1200V / 200A 2 in one-package

■ Features

- VCE(sat) classified for easy parallel connection
- High speed switching
- Voltage drive
- Low inductance module structure

■ Applications

- Inverter for Motor drive
- AC and DC Servo drive amplifier
- Uninterruptible power supply
- Industrial machines, such as Welding machines



■ Maximum ratings and characteristics

● Absolute maximum ratings (at Tc=25°C unless otherwise specified)

Item	Symbol	Rating	Unit
Collector-Emitter voltage	V _{CEs}	1200	V
Gate-Emitter voltage	V _{GEs}	±20	V
Collector current	Continuous	I _c	200
	1ms	I _c pulse	400
		-I _c	200
	1ms	-I _c pulse	400
Max. power dissipation	P _c	1500	W
Operating temperature	T _j	+150	°C
Storage temperature	T _{stg}	-40 to +125	°C
Isolation voltage	V _{is}	AC 2500 (1min.)	V
Screw torque	Mounting *1	3.5	N·m
	Terminals *2	4.5	N·m

*1: Recommendable value : 2.5 to 3.5 N·m (M5) or (M6)

*2: Recommendable value : 3.5 to 4.5 N·m (M6)

● Electrical characteristics (at Tj=25°C unless otherwise specified)

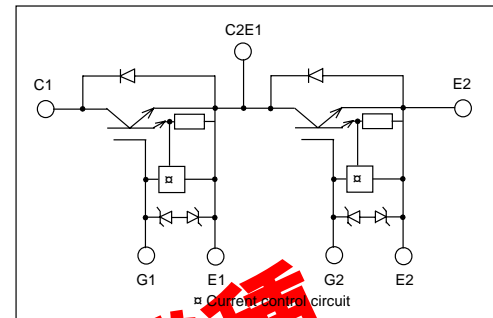
Item	Symbol	Characteristics			Conditions	Unit
		Min.	Typ.	Max.		
Zero gate voltage collector current	I _{ces}	-	-	2.0	V _{GE} =0V, V _{CE} =1200V	mA
Gate-Emitter leakage current	I _{ges}	-	-	30	V _{CE} =0V, V _{GE} =±20V	µA
Gate-Emitter threshold voltage	V _{GE(th)}	4.5	-	7.5	V _{CE} =20V, I _c =200mA	V
Collector-Emitter saturation voltage	V _{CE(sat)}	-	-	3.3	V _{GE} =15V, I _c =200A	V
Input capacitance	C _{ies}	-	32000	-	V _{GE} =0V	pF
Output capacitance	C _{oes}	-	11600	-	V _{CE} =10V	
Reverse transfer capacitance	C _{res}	-	10320	-	f=1MHz	
Turn-on time	t _{on}	-	0.65	1.2	V _{CC} =600V	µs
	t _r	-	0.25	0.6	I _c =200A	
Turn-off time	t _{off}	-	0.85	1.5	V _{GE} =±15V	
	t _f	-	0.35	0.5	R _G =4.7ohm	
Diode forward on voltage	V _F	-	-	3.0	I _F =200A, V _{GE} =0V	V
Reverse recovery time	t _{rr}	-	-	0.35	I _F =200A	µs

● Thermal resistance characteristics

Item	Symbol	Characteristics			Conditions	Unit
		Min.	Typ.	Max.		
Thermal resistance	R _{th(j-c)}	-	-	0.085	IGBT	°C/W
	R _{th(j-c)}	-	-	0.18	Diode	°C/W
	R _{th(c-f)*}	-	0.025	-	the base to cooling fin	°C/W

*: This is the value which is defined mounting on the additional cooling fin with thermal compound

■ Equivalent Circuit Schematic

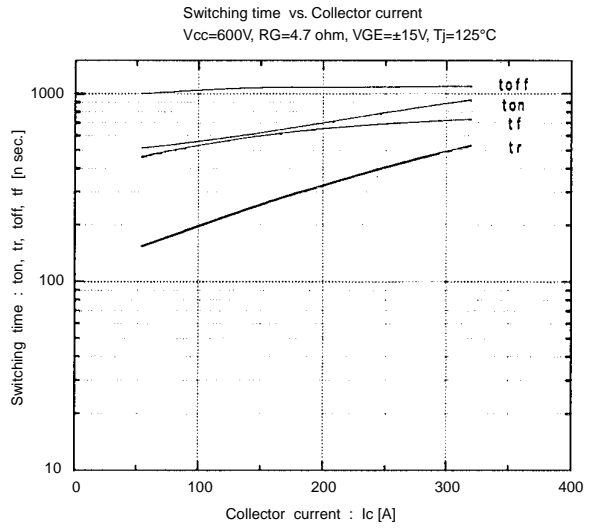
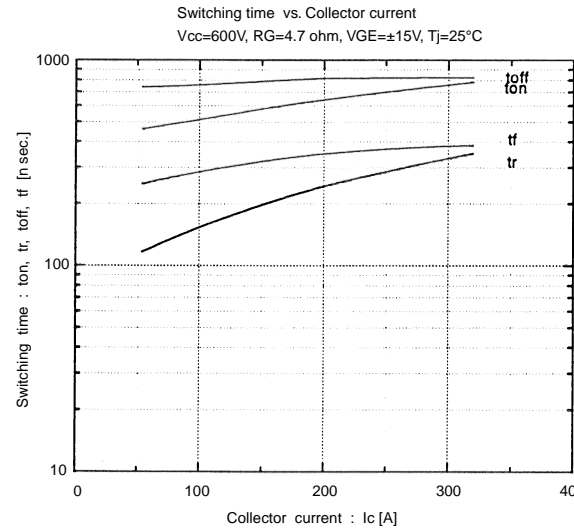
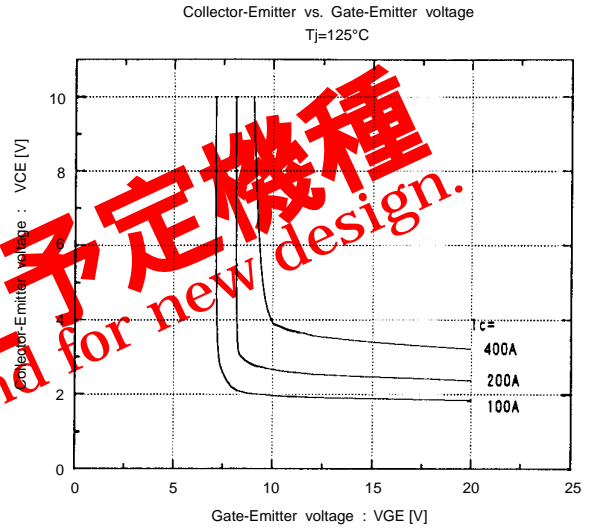
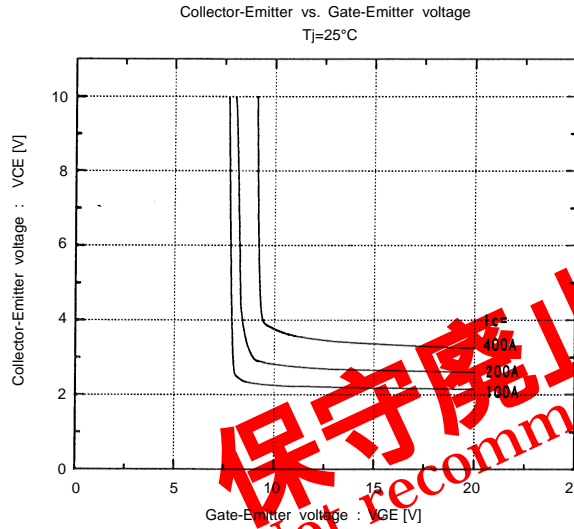
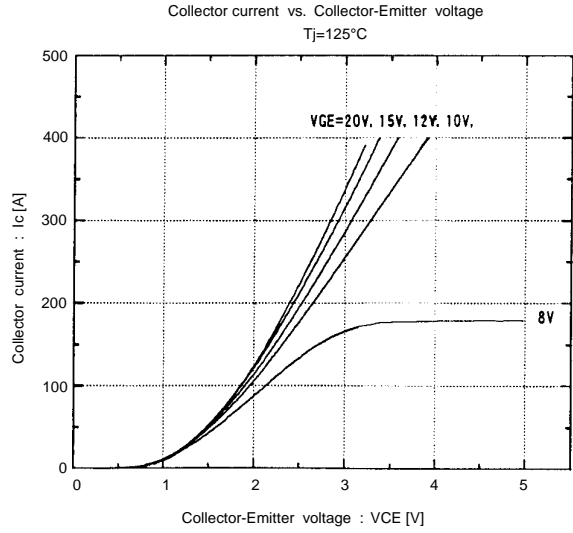
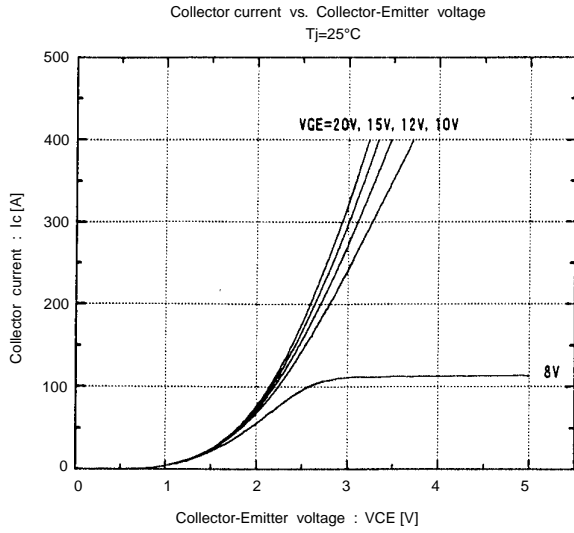


● VCE(sat) classification

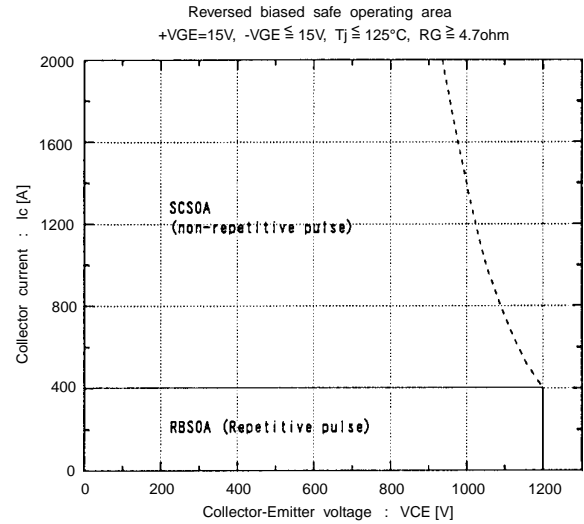
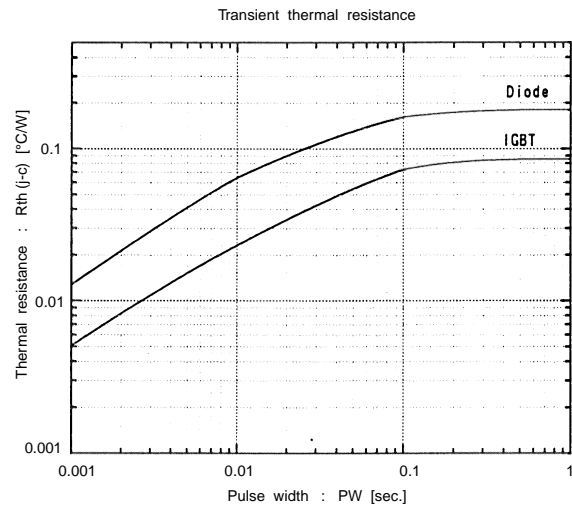
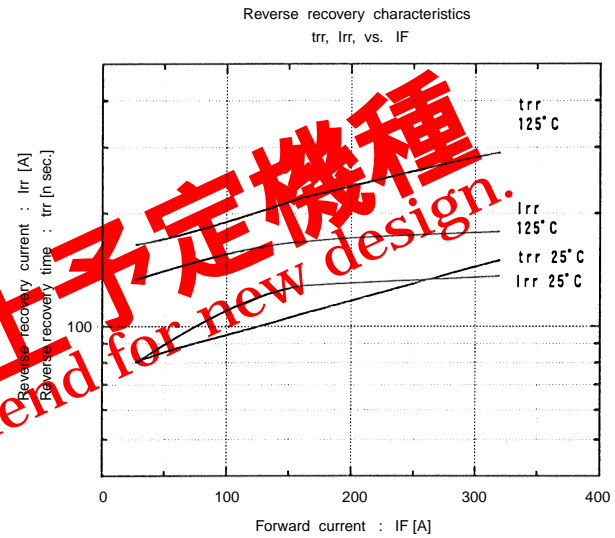
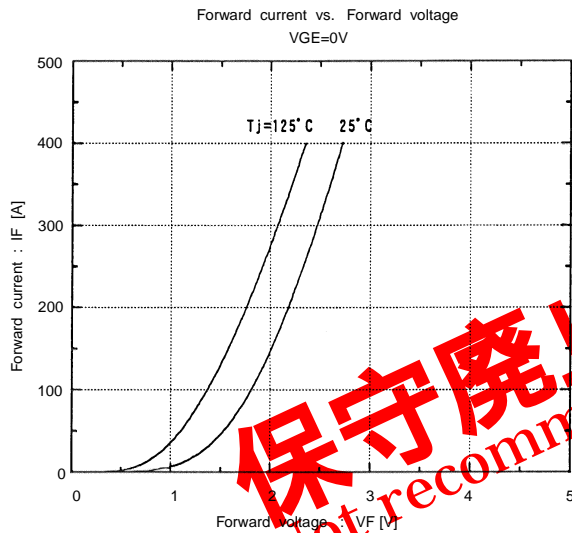
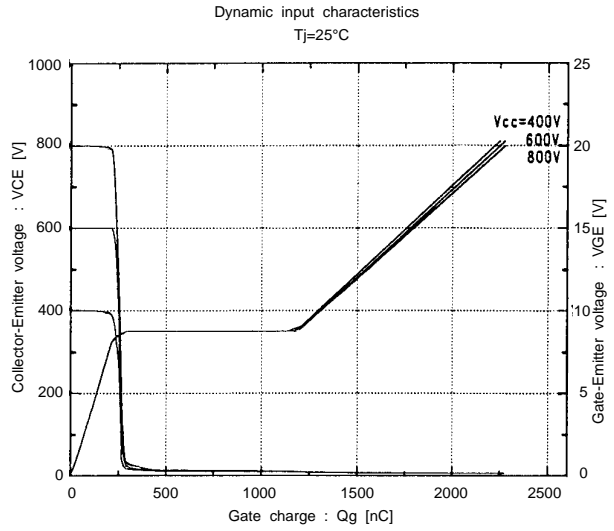
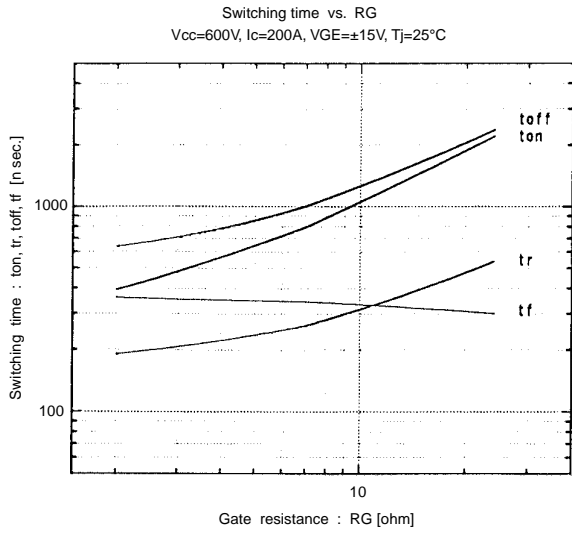
Rank	Length	Conditions
F	2.25 to 2.50V	I _c = 200A V _{GE} = 15V T _j = 25°C
A	2.40 to 2.65V	
B	2.65 to 2.80V	
C	2.70 to 2.95V	
D	2.85 to 3.10V	
E	3.00 to 3.30V	

保守禁止予定機種
 Not recommend for new design

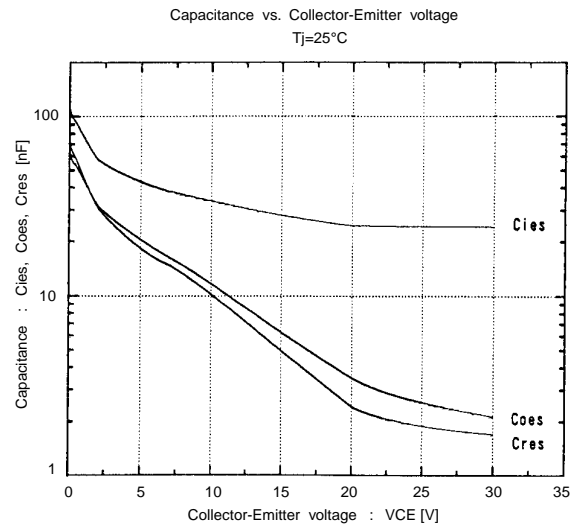
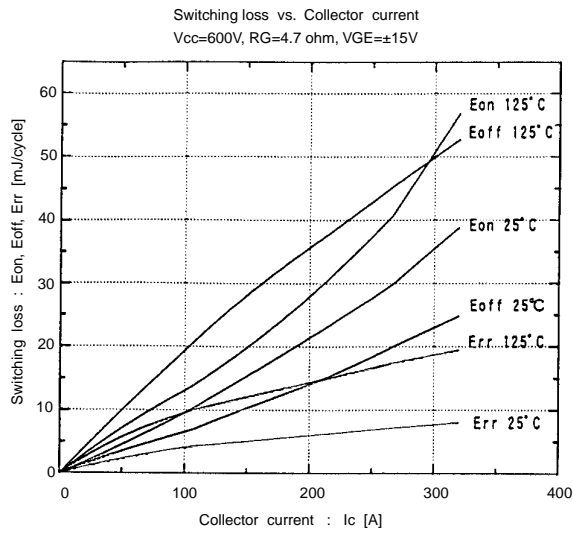
■ Characteristics (Representative)



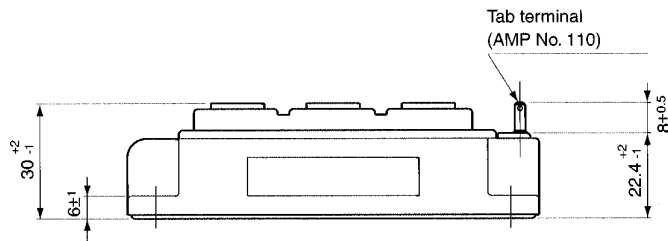
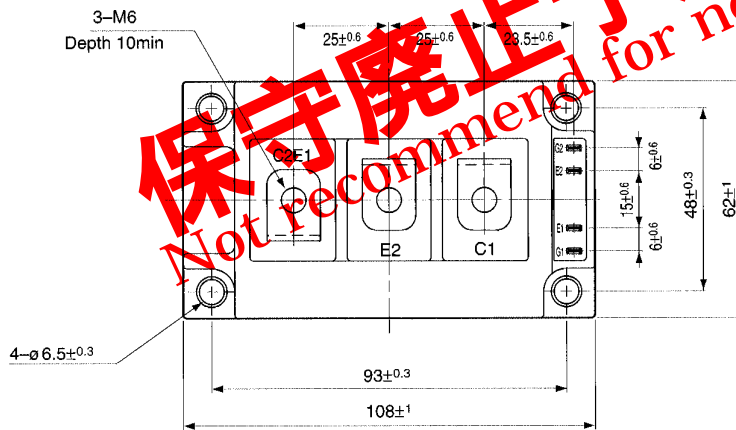
保守禁止 予定機種
Not recommend for new design.



保守廃止予定機種
 Not recommend for new design.



■ Outline Drawings, mm



Mass : 370g

保守禁止予定機種
Not recommend for new design.